

C230, C231, C230()3, C231()3, C232, C233 SERIES

High-reliability discrete products and engineering services since 1977

SILICON CONTROLLED RECTIFIERS

FEATURES

- Available as "HR" (high reliability) screened per MIL-PRF-19500, JANTX level. Add "HR" suffix to base part number.
- Available as non-RoHS (Sn/Pb plating), standard, and as RoHS by adding "-PBF" suffix.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak repetitive off state voltage ⁽¹⁾			
(T _J = -40 to +100°C)			
C230F, C231F, C230F3, C231F3, C232F, C233F		50	
C230A, C231A, C230A3, C231A3, C232A, C233A		100	
C230B, C231B, C230B3, C231B3, C232B, C233B	V _{RRM} , V _{DRM}	200	Volts
C230C, C231C, C230C3, C231C3, C232C, C233C		300	
C230D, C231D, C230D3, C231D3, C232D, C233D		400	
C230E, C231E, C230E3, C231E3, C232E, C233E		500	
C230M, C231M, C230M3, C231M3, C232M, C233M		600	
Peak non-repetitive reverse voltage			
(T _J = -40 to +100°C)			
C230F, C231F, C230F3, C231F3, C232F, C233F		75	
C230A, C231A, C230A3, C231A3, C232A, C233A		150	
C230B, C231B, C230B3, C231B3, C232B, C233B	V _{RSM}	300	Volts
C230C, C231C, C230C3, C231C3, C232C, C233C		400	
C230D, C231D, C230D3, C231D3, C232D, C233D		500	
C230E, C231E, C230E3, C231E3, C232E, C233E		600	
C230M, C231M, C230M3, C231M3, C232M, C233M		720	
Forward current RMS	I _{T(RMS)}	25	Amps
Peak surge current			Amos
(one cycle, 60Hz, T _c = -40 to +100°C)	I _{TSM}	250	Amps
Circuit fusing considerations	l ² t		A ² s
(T _c = -40 to +100°C, t = 8.3ms)	I L	260	A 3
Peak gate power	Р _{бм}	5	Watts
Average gate power	P _{G(AV)}	0.5	Watts
Peak forward gate current	I _{GM}	2	Amps
Operating junction temperature range	٦	-40 to +100	°C
Storage temperature range	T _{stg}	-40 to +125	°C
Mounting torque		30	In. lb.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Maximum	Unit
Thermal resistance, junction to case			
Pressfit	R _{eJC}	1	°C/W
Isolated stud		1.15	



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Characteristic	Symbol	Min.	Тур.	Max.	Unit
Peak forward or reverse blocking current					
(Rated V_{DRM} or V_{RRM} , gate open)					
T _c = 25°C	Idrm, Irrm	-	-	10	μΑ
T _c = 100°C		-	-	1	mA
Forward "on" voltage	V _{TM}				Volts
(I_{TM} = 100A peak, pulse width \leq 1ms, duty cycle \leq 2%)	VTM	-	-	1.9	VOILS
Gate trigger current (C230, C230()3, C232 series)	Igt				mA
$(V_D = 12V, R_L = 120\Omega)$		-	-	25	
$(V_D = 12V, R_L = 60\Omega, T_C = -40^{\circ}C)$		-	-	40	
Gate trigger current (C231, C231()3, C233 series)	Igt				mA
$(V_D = 12V, R_L = 120\Omega)$		-	-	9	
$(V_D = 12V, R_L = 60\Omega, T_C = -40^{\circ}C)$		-	-	20	
Gate trigger voltage (continuous dc)					Volts
$(V_D = 12V, R_L = 120\Omega)$	Vgt	-	-	1.5	
$(V_D = 12V, R_L = 60\Omega, T_C = -40^{\circ}C)$		-	-	2	
$(V_D = Rated V_{DRM}, R_L = 1000\Omega, T_C = 100^{\circ}C)$		0.2	-	-	
Holding current	Ін				mA
$(V_D = 24V, \text{ gate open}, I_T = 0.5A)$					
T _C = 25°C		-	-	50	
T _c = -40°C		-	-	100	
Turn-on time (t _d +t _r)	t _{gt}				μs
$(I_{TM} = 25A, I_{GT} = 40mA, V_D = Rated V_{DRM})$		-	1	-	
Turn-off time	tq				μs
(I_{TM} = 10A, I_R = 10A, pulse width = 50µs, dv/dt = 20V/µs,					
V _D = Rated V _{DRM})		-	25	-	
(T _c = 100°C)		-	35	-	
Forward voltage application rate	dv/dt				V/µs
(V _D = rated V _{DRM} , T _C = 100°C)		-	100	-	

ELECTRICAL CHARACTERISTICS ($T_c = 25^{\circ}C$ unless otherwise specified)



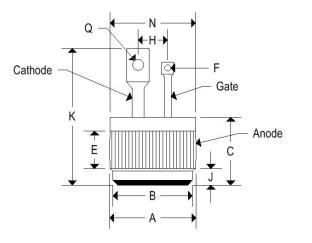
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MECHANICAL CHARACTERISTICS

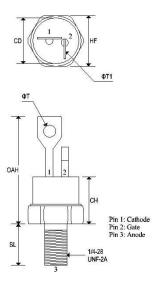
Case	Digi PF2 (C232 and C233 SERIES)
Marking	Body painted, alpha-numeric



	DIGI PF2			
	Inc	Inches Millimeters		
	Min	Max	Min	Max
Α	0.501	0.505	12.730	12.830
В	0.465	0.475	11.810	12.060
С	0.330	0.380	8.390	9.650
Е	0.100	-	2.540	-
F	0.035	0.085	0.890	2.160
J	0.080	0.097	2.040	2.460
Κ	-	0.800	-	20.320
Ν	-	0.510	-	12.950
Q	0.065	0.160	1.650	4.060

MECHANICAL CHARACTERISTICS

Case TO-48 (C230,C231)	
Marking	Body painted, alpha-numeric
Polarity	Cathode is stud



	TO-48				
	Inches Millimeters				
	Min	Max	Min Max		
CD	-	0.543	-	13.793	
СН	-	0.550	-	13.970	
HF	0.544	0.563	13.817	14.301	
OAH	-	1.193	-	30.303	
SL	0.422	0.453	10.718	11.507	
ФТ	0.125	0.165	3.175	4.191	
ΦT 1	0.060	0.075	1.524	1.905	



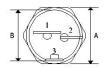
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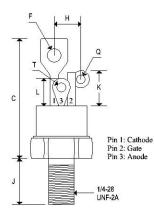
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MECHANICAL CHARACTERISTICS

Case	TO-48 ISO (C230()3, C231()3 SERIES)		
Marking	Body painted, alpha-numeric		
Polarity	Cathode is stud		





	TO-48 ISO			
	Inches Millimeters			
	Min	Max	Min	Max
Α	0.551	0.559	14.000	14.200
В	0.501	0.505	12.730	12.830
С	-	1.280	-	32.510
F	-	0.160	-	4.060
Η	-	0.265	-	6.730
J	0.420	0.455	10.670	11.560
Κ	0.300	0.350	7.620	8.890
L	0.255	0.275	6.480	6.990
Q	0.055	0.085	1.400	2.160
Т	0.135	0.150	3.430	3.810

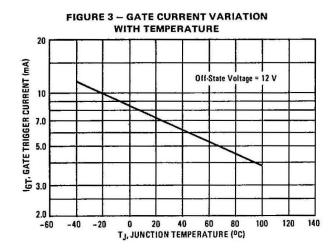
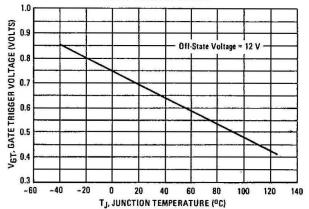


FIGURE 4 – GATE VOLTAGE VARIATION WITH TEMPERATURE



Rev. 20171114